

X3-Class HiPerFET™ **Power MOSFET**

IXFP90N20X3M

(Electrically Isolated Tab)

N-Channel Enhancement Mode

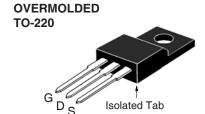


Characteristic Values

10.5

12.8 $m\Omega$

V _{DSS}	=	200V
I _{D25}	=	90A
R _{DS(on)}	\leq	12.8m Ω



G = Gate	D = Drain
S = Source	

Symbol	Test Conditions	Maximum Ratings		
V _{DSS}	T _J = 25°C to 150°C	200	V	
V _{DGR}	$T_{_{ m J}}$ = 25°C to 150°C, $R_{_{ m GS}}$ = 1M Ω	200	V	
V _{GSS}	Continuous	±20	V	
V _{GSM}	Transient	±30	V	
I _{D25}	$T_{c} = 25$ °C, Limited by T_{iim}	90	A	
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	220	Α	
I _A	T _C = 25°C	45	A	
E _{AS}	T _C = 25°C	1.5	J	
dv/dt	$I_{S} \leq I_{DM}, V_{DD} \leq V_{DSS}, T_{J} \leq 150^{\circ}C$	50	V/ns	
P_{D}	T _C = 25°C	36	W	
T _J		-55 +150	°C	
T_{JM}		150	°C	
T _{stg}		-55 +150	°C	
T,	Maximum Lead Temperature for Soldering	300	°C	
T _{SOLD}	1.6 mm (0.062in.) from Case for 10s	260	°C	
V _{ISOL}	50/60 Hz, 1 Minute	2500	V~	
M _d	Mounting Torque	1.13 / 10	Nm/lb.in	
Weight		2.5	g	

Features

- International Standard Package
- Plastic Overmolded Tab
- Low R_{DS(ON)} and Q_G
 Avalanche Rated
- 2500V~ Electrical Isolation
- Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

(T _J = 25°C, Unless Otherwise Specified)		Min.	Тур.	Max		
BV _{DSS}	$V_{GS} = 0V, I_{D} = 250\mu A$		200			V
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 1.5 mA$		2.5		4.5	V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$				±100	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$	T _J = 125°C			5 300	μ Α μ Α

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

 $V_{GS} = 10V$, $I_D = 45A$, Note 1

Test Conditions

Symbol





Symbol Test Conditions $(T_J = 25^{\circ}C, Unless Otherwise Specified)$		Chai Min.	acteristic Typ.	Values Max
g _{fs}	$V_{DS} = 10V, I_{D} = 45A, \text{ Note 1}$	40	67	S
R_{Gi}	Gate Input Resistance		1.4	Ω
C _{iss}			5420	pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		930	pF
C _{rss}			4	pF
	Effective Output Capacitance			
$C_{o(er)}$	Energy related $\int V_{gs} = 0V$		420	pF
C _{o(tr)}	Time related $\int V_{DS}^{dS} = 0.8 \cdot V_{DSS}$		1300	pF
t _{d(on)}	Resistive Switching Times		22	ns
t _r	<u>-</u>		26	ns
t _{d(off)}	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_D = 45A$		62	ns
\mathbf{t}_{f}	$R_{\rm g} = 5\Omega$ (External)		13	ns
$Q_{g(on)}$			78	nC
Q _{gs}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 45A$		23	nC
\mathbf{Q}_{gd}			22	nC
R _{thJC}				3.5 °C/W
R _{thCS}			0.50	°C/W

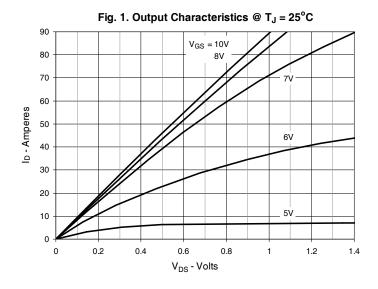
MYZ	INCHES		MILLIMETERS		
214	MIN	MAX	MIN	MAX	
Α	.177	.193	4.50	4.90	
A1	.092	.108	2.34	2.74	
A2	.101	.117	2.56	2.96	
b	.028	.035	0.70	0.90	
b1	.050	.058	1.27	1.47	
С	.018	.024	0.45	0.60	
D	.617	.633	15.67	16.07	
E	.392	.408	9.96	10.36	
е	.100 BSC		2.54	BSC	
Н	.255	.271	6.48	6.88	
L	.499	.523	12.68	13.28	
L1	.119	.135	3.03	3.43	
ØΡ	.121	.129	3.08	3.28	
Q	.126	.134	3.20	3.40	

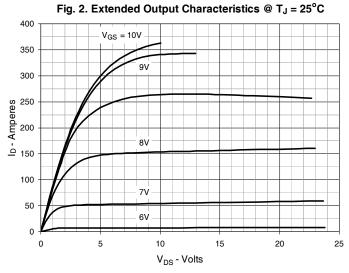
Source-Drain Diode

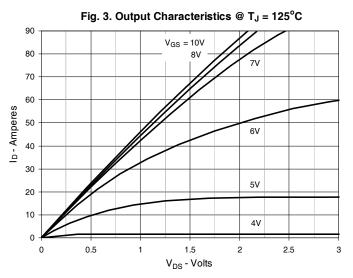
Symbol Test Conditions		Characteristic Values			
$(1_{J} = 25^{\circ})$	C, Unless Otherwise Specified)	Min.	Тур.	Max	
Is	$V_{GS} = 0V$			90	Α
I _{SM}	Repetitive, Pulse Width Limited by $T_{_{JM}}$			360	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.4	V
t _{rr}	$I_F = 45A$, -di/dt = 100A/ μ s		95		ns
$\mathbf{Q}_{_{\mathrm{RM}}}$	V _p = 100V		360		nC
I _{RM}) v _R = 100 v		7.6		A

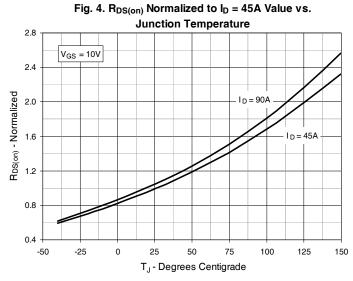
Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

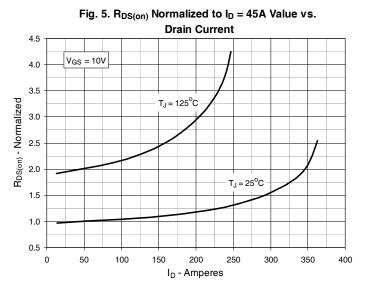


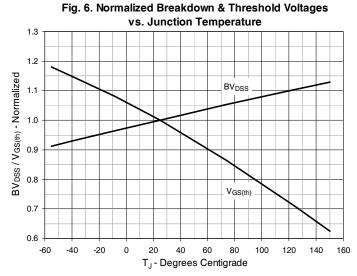






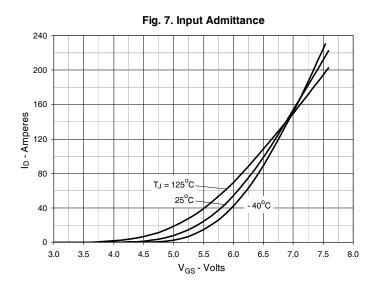


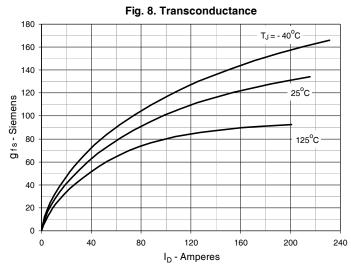


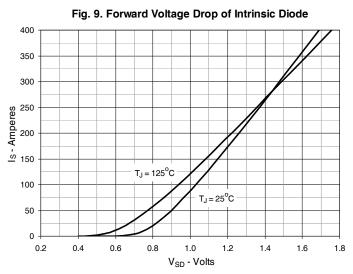


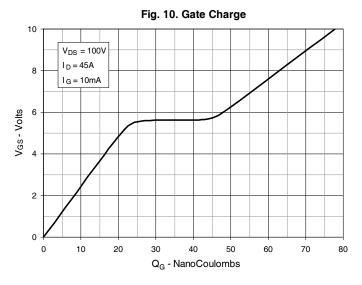
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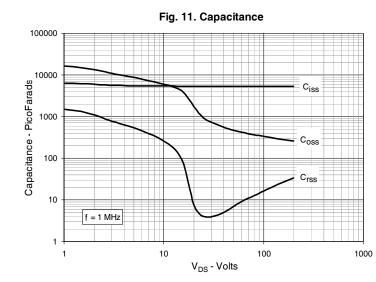


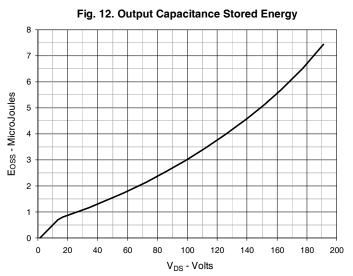












IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

Fig. 13. Forward-Bias Safe Operating Area

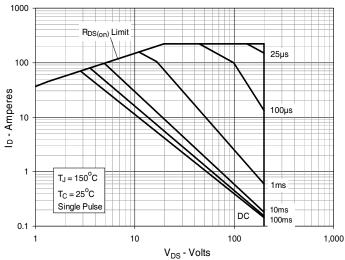
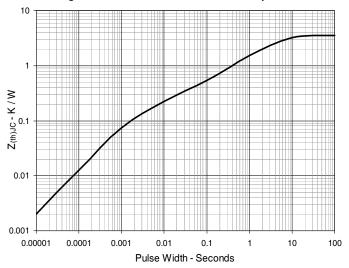


Fig. 14. Maximum Transient Thermal Impedance









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